8550

PNP Silicon Epitaxial Planar Transistor

for switching and amplifier applications. Especially suitable for AF-driver stages and low power output stages.

The transistor is subdivided into four groups, B, C, D and E, according to its DC current gain.



1. Emitter 2. Base 3. Collector TO-92 Plastic Package

Absolute Maximum Ratings (T_a = 25°C)

Parameter	Symbol	Value	Unit	
Collector Base Voltage	-V _{CBO}	40	V	
Collector Emitter Voltage	-V _{CEO}	25	V	
Emitter Base Voltage	-V _{EBO}	6	V	
Collector Current	-I _C	800	mA	
Base Current	-I _B	100	mA	
Power Dissipation	P _{tot}	625	mW	
Junction Temperature	Tj	150	°C	
Storage Temperature Range	T _{stg}	- 55 to + 150	C°	

Characteristics at T_a = 25°C

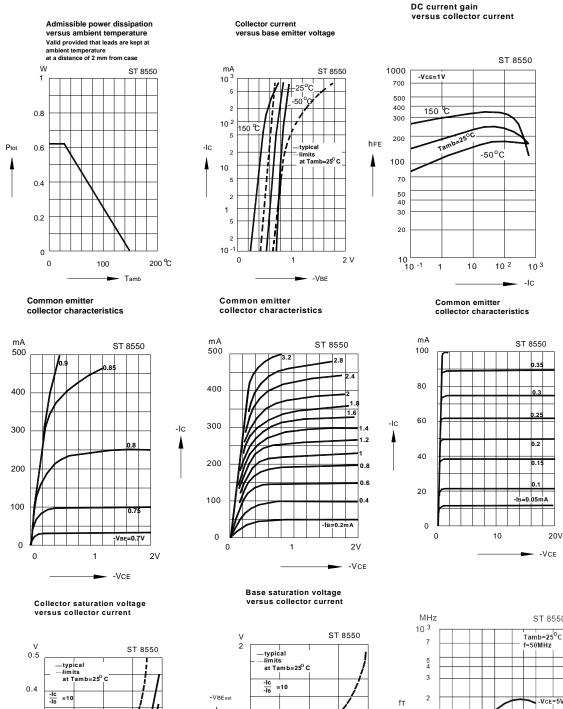
Parameter	Symbol	Min.	Тур.	Max.	Unit
DC Current Gain at $-V_{CE} = 1 \text{ V}, -I_C = 100 \text{ mA}$ Current Gain Group B C D E	h _{FE} h _{FE} h _{FE} h _{FE}	70 120 160 300	- - -	120 200 300 380	- - -
at $-V_{CE} = 1 \text{ V}, -I_{C} = 350 \text{ mA}$	h _{FE}	60	-	-	-
Collector Base Cutoff Current at $-V_{CB} = 35 \text{ V}$	-I _{CBO}	-	-	100	nA
Collector Base Breakdown Voltage at $-I_C = 10 \ \mu A$	-V _{(BR)CBO}	40	-	-	V
Collector Emitter Breakdown Voltage at $-I_c = 2 \text{ mA}$	-V _{(BR)CEO}	25	-	-	V
Emitter Base Breakdown Voltage at -I _E = 100 μA	-V _{(BR)EBO}	6	-	-	V
Collector Emitter Saturation Voltage at $-I_C = 500 \text{ mA}$, $-I_B = 50 \text{ mA}$	-V _{CE(sat)}	-	-	0.5	V
Base Emitter Saturation Voltage at $-I_{C} = 500 \text{ mA}$, $-I_{B} = 50 \text{ mA}$	-V _{BE(sat)}	-	-	1.2	V
Gain Bandwidth Product at $-V_{CE} = 5 V$, $-I_C = 10 mA$, f = 50 MHz	f _T	-	100	-	MHz
Collector Base Capacitance at $-V_{CB} = 10 \text{ V}, \text{ f} = 1 \text{ MHz}$	C _{ob}	-	12	-	pF

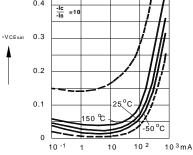


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Dated : 12/04/2016 Rev: 02

510²2

-Ic

20V

- -VCE

ST 8550

-VCE=5V

5 10 ³mA

1V

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